

L Number	Hits	Search Text	DB	Time stamp
-	1	("20040094759").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/15 15:55
-	6160	(438/571,586,597,602,605,610,652,658,666).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/15 13:24
-	204	(group near (three III) (GaN "GaN" "Ga N" gallium near nitride) (AlGaN "AlGaN" "Al Ga N" aluminum near gallium near nitride Gaaln "Gaaln" "Ga Al N")) and ((438/571,586,597,602,605,610,652,658,666).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/15 15:56
-	26	((GaN "GaN" "Ga N" gallium near nitride) and (AlGaN "AlGaN" "Al Ga N" aluminum near gallium near nitride Gaaln "Gaaln" "Ga Al N")) and ((438/571,586,597,602,605,610,652,658,666).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/15 11:48
-	265	((GaN "GaN" "Ga N" gallium near nitride) and (AlGaN "AlGaN" "Al Ga N" aluminum near gallium near nitride Gaaln "Gaaln" "Ga Al N")) and (recess\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/15 11:48
-	74	((GaN "GaN" "Ga N" gallium near nitride) and (AlGaN "AlGaN" "Al Ga N" aluminum near gallium near nitride Gaaln "Gaaln" "Ga Al N")) and (recess\$3)) and (h near fet hfet heterojunction hetero junction)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/15 13:22
-	277	ohmic with ((ti "ti" titanium) and (al "al" aluminum) and (au "au" gold) and (ni "ni" nickel))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/15 13:24
-	116	ohmic with ((ti "ti" titanium) with (al "al" aluminum) with (au "au" gold) with (ni "ni" nickel))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/15 13:32
-	6160	(438/571,586,597,602,605,610,652,658,666).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/15 13:24
-	5	(ohmic with ((ti "ti" titanium) with (al "al" aluminum) with (au "au" gold) with (ni "ni" nickel))) and ((438/571,586,597,602,605,610,652,658,666).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/15 13:24
-	23	(ohmic with ((ti "ti" titanium) and (al "al" aluminum) and (au "au" gold) and (ni "ni" nickel))) and ((438/571,586,597,602,605,610,652,658,666).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/15 13:30
-	10	ohmic same ((ti "ti" titanium) with (al "al" aluminum) with (au "au" gold) with (ni "ni" nickel)) same (heat\$3 anneal\$4) same alloy\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/15 13:33
-	1	6492669.URPN.	USPAT	2004/06/15 14:02
-	2	("5471073" "6316793").PN.	USPAT	2004/06/15 14:02

	2	("6492669").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/15 14:05
	1386	electron near gas and (438/\$6 257/\$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/15 15:56
	328	(group near (three III) (GaN "GaN" "Ga N" gallium near nitride) (AlGaN "AlGaN" "Al Ga N" aluminum near gallium near nitride GaIn "GaIn" "Ga Al N")) and (electron near gas and (438/\$6 257/\$6))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/15 16:32
	2403	etch\$5 with ecr	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/15 16:33
	69	etch\$5 with ecr and ((GaN "GaN" "Ga N" gallium near nitride) and (AlGaN "AlGaN" "Al Ga N" aluminum near gallium near nitride GaIn "GaIn" "Ga Al N"))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/15 16:33
	634	etch\$5 with ecr with rie	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/15 16:33
	26	(etch\$5 with ecr and ((GaN "GaN" "Ga N" gallium near nitride) and (AlGaN "AlGaN" "Al Ga N" aluminum near gallium near nitride GaIn "GaIn" "Ga Al N")) and (etch\$5 with ecr with rie)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/15 16:33